#### RN2101MFV to RN2106MFV

Bipolar Transistors Silicon PNP Epitaxial Type (PCT Process)(Bias Resistor built-in Transistor)

### RN2101MFV/02MFV/03MFV/04MFV/05MFV/06MFV

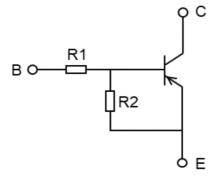
#### 1. Applications

- Switching
- Inverter Circuits
- Interfacing
- Driver Circuits

#### 2. Features

- (1) AEC-Q101 qualified (Please see the orderable part number list)
- (2) Ultra-small package, suited to very high density mounting
- (3) The integrated bias resistor reduces the number of external parts required, making it possible to reduce system size and assembly time.
- (4) Toshiba offers transistors with a wide range of resistance to accommodate various circuit designs.
- (5) Complementary to RN1101MFV to RN1106MFV

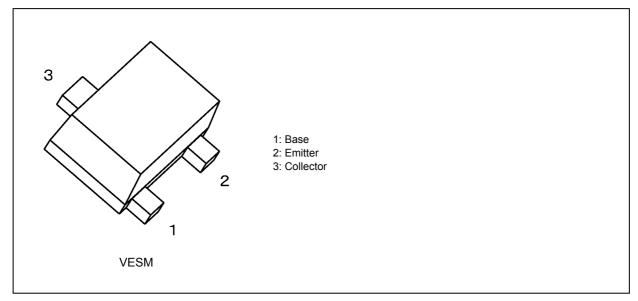
#### 3. Equivalent Circuit



#### 4. Bias Resistor Values

Part No.	R1 (kΩ)	R2 (kΩ)
RN2101MFV	4.7	4.7
RN2102MFV	10	10
RN2103MFV	22	22
RN2104MFV	47	47
RN2105MFV	2.2	47
RN2106MFV	4.7	47

#### 5. Packaging and Pin Assignment



#### 6. Orderable part number

Orderable part number		AEC-Q101	AEC-Q101		Note		
RN2101MFV	RN2101MFV,L3F			General Use			
	RN2101MFV,L3XGF	YES	(Note 1)	Unintended Use	(Note 1)		
	RN2101MFV,L3XHF	YES		Automotive Use			
RN2102MFV	RN2102MFV,L3F	_		General Use			
	RN2102MFV,L3XGF	YES	(Note 1)	Unintended Use	(Note 1)		
	RN2102MFV,L3XHF	YES		Automotive Use			
RN2103MFV	RN2103MFV,L3F	_		General Use			
	RN2103MFV,L3XGF	YES	(Note 1)	Unintended Use	(Note 1)		
	RN2103MFV,L3XHF	YES		Automotive Use			
RN2104MFV	RN2104MFV,L3F	_		General Use			
	RN2104MFV,L3XGF	YES	(Note 1)	Unintended Use	(Note 1)		
	RN2104MFV,L3XHF	YES		Automotive Use			
RN2105MFV RN2105MFV,L3F		_		General Use			
	RN2105MFV,L3XGF	YES	(Note 1)	Unintended Use	(Note 1)		
	RN2105MFV,L3XHF	YES		Automotive Use			
RN2106MFV	RN2106MFV,L3F	_		General Use			
	RN2106MFV,L3XGF	YES	(Note 1)	Unintended Use	(Note 1)		
	RN2106MFV,L3XHF	YES		Automotive Use			

Note 1: For more information, please contact our sales or use the inquiry form on our website.

#### 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25$ °C)

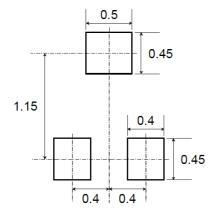
Characteristics	Symbol	Rating	Unit	
Collector-base voltage	RN2101MFV to RN2106MFV	V <sub>CBO</sub>	-50	V
Collector-emitter voltage		V <sub>CEO</sub>	-50	
Emitter-base voltage	RN2101MFV to RN2104MFV	V <sub>EBO</sub>	-10	]
	RN2105MFV,RN2106MFV		-5	
Collector current	RN2101MFV to RN2106MFV	I <sub>C</sub>	-100	mA
Collector power dissipation		P <sub>C</sub> (Note 1)	150	mW
Junction temperature		Tj	150	°C
Storage temperature		T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on an FR4 board (25.4 mm  $\times$  25.4 mm  $\times$  1.6 mm)

#### 8. Land Pattern Dimensions (for reference only)

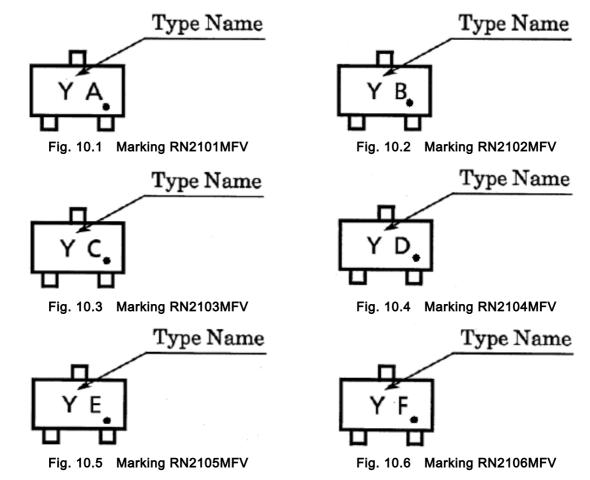


Unit: mm

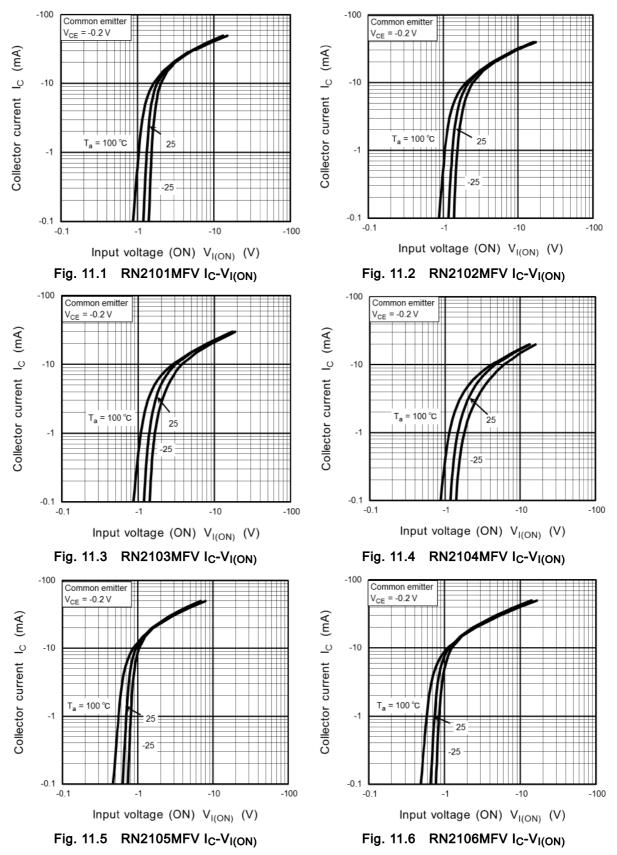
#### 9. Electrical Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2101MFV to	$I_{CBO}$ $V_{CB}$ = -50 V, $I_E$ = 0 mA		—	_	-100	nA
	RN2106MFV	I <sub>CEO</sub>	V <sub>CE</sub> = -50 V, I <sub>B</sub> = 0 mA	—	_	-500	
Emitter cut-off current	RN2101MFV	I <sub>EBO</sub>	V <sub>EB</sub> = -10 V, I <sub>C</sub> = 0 mA	-0.82	—	-1.52	mA
	RN2102MFV			-0.38	—	-0.71	
	RN2103MFV			-0.17	_	-0.33	
	RN2104MFV			-0.082	—	-0.15	
	RN2105MFV		V <sub>EB</sub> = -5 V, I <sub>C</sub> = 0 mA	-0.078	—	-0.145	
	RN2106MFV			-0.074	—	-0.138	
DC current gain	RN2101MFV	h <sub>FE</sub>	V <sub>CE</sub> = -5 V, I <sub>C</sub> = -10 mA	30	—	_	_
	RN2102MFV			50	—	_	
	RN2103MFV			70	—	_	
	RN2104MFV			80			
	RN2105MFV			80	—	_	
	RN2106MFV			80	_	_	
Collector-emitter saturation voltage	RN2101MFV to RN2106MFV	V <sub>CE(sat)</sub>	I <sub>C</sub> = -5 mA, I <sub>B</sub> = -0.5 mA	—	-0.1	-0.3	V
Input voltage (ON)	RN2101MFV	V <sub>I(ON)</sub>	V <sub>CE</sub> = -0.2 V, I <sub>C</sub> = -5 mA	-1.1		-2.0	V
	RN2102MFV			-1.2	_	-2.4	
	RN2103MFV			-1.3	_	-3.0	
	RN2104MFV			-1.5	_	-5.0	
	RN2105MFV			-0.6	_	-1.1	
	RN2106MFV			-0.7		-1.3	
Input voltage (OFF)	RN2101MFV to RN2104MFV	V <sub>I(OFF)</sub>	$V_{CE}$ = -5 V, I <sub>C</sub> = -0.1 mA	-1.0	—	-1.5	V
	RN2101MFV to RN2106MFV			-0.5	—	-0.8	
Transition frequency	RN2101MFV to RN2106MFV	f <sub>T</sub>	V <sub>CE</sub> = -10 V, I <sub>C</sub> = -5 mA	—	250	_	MHz
Collector output capacitance	RN2101MFV to RN2106MFV	C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0 mA, f = 1 MHz	—	0.9	—	pF
Input resistance	RN2101MFV	R <sub>1</sub>	-	3.29	4.7	6.11	kΩ
	RN2102MFV			7	10	13	
	RN2103MFV			15.4	22	28.6	
	RN2104MFV			32.9	47	61.1	
	RN2105MFV			1.54	2.2	2.86	
	RN2106MFV			3.29	4.7	6.11	
Resistor ratio	RN2101MFV to RN2104MFV	R1/R2	-	0.8	1.0	1.2	_
	RN2105MFV			0.0376	0.0468	0.0562	
	RN2106MFV			0.08	0.1	0.12	

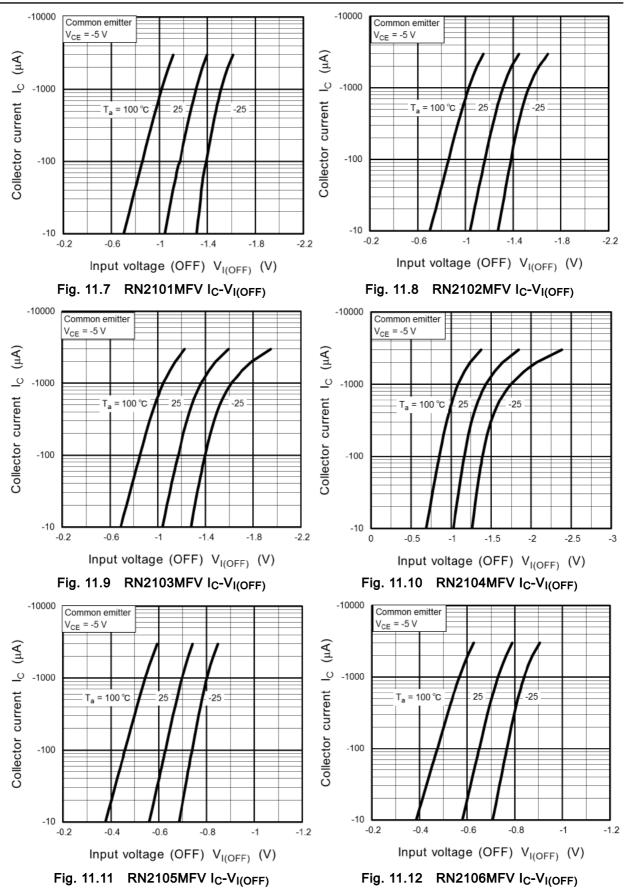
#### 10. Marking



#### 11. Characteristics Curves (Note)

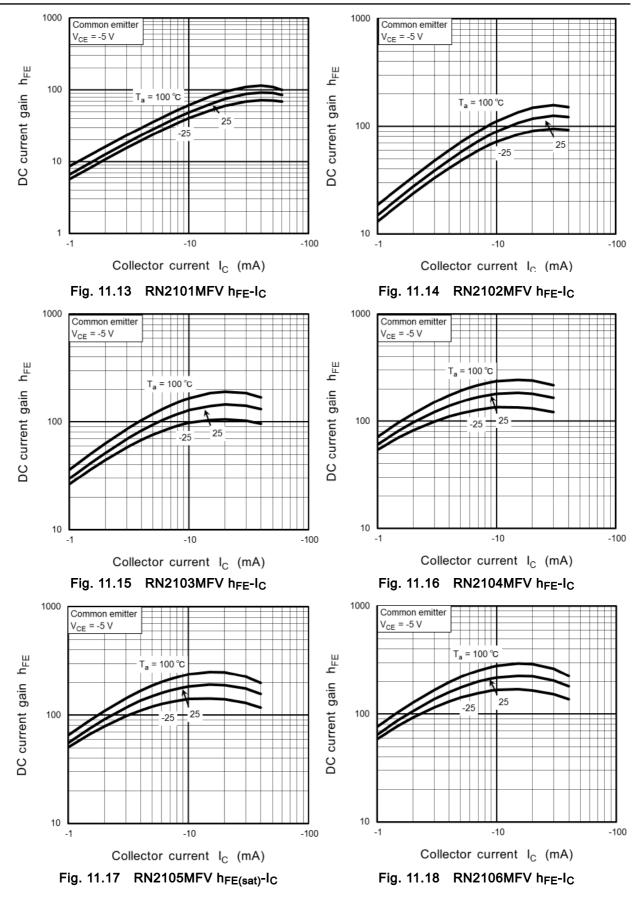


#### RN2101MFV to RN2106MFV



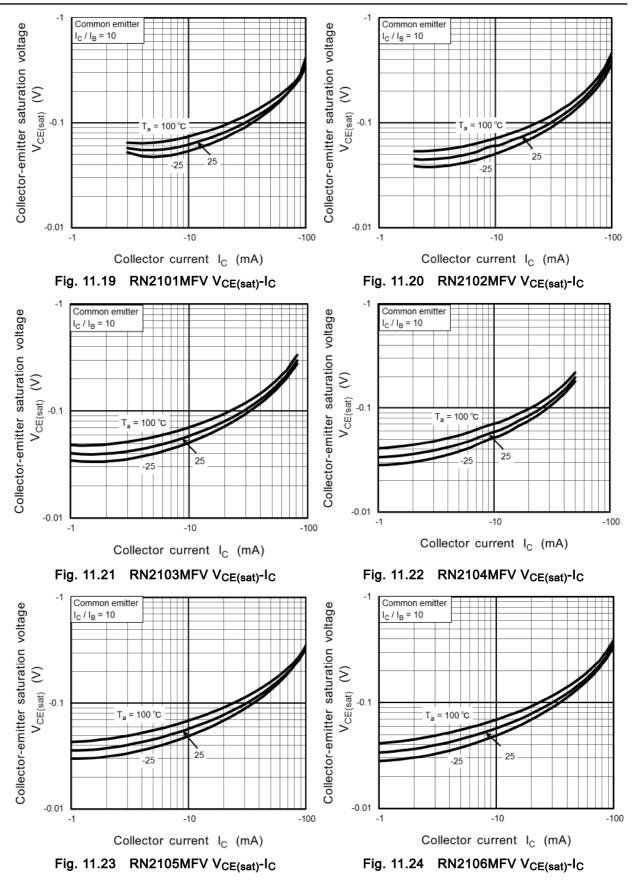


#### RN2101MFV to RN2106MFV





#### RN2101MFV to RN2106MFV



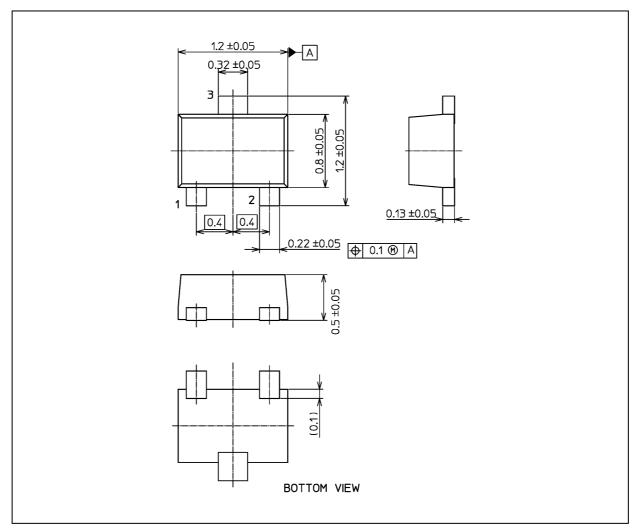
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



#### RN2101MFV to RN2106MFV

#### Package Dimensions

Unit: mm



Weight: 1.5 mg (typ.)

Package Name(s)			
TOSHIBA: 1-1Q1S			
Nickname: VESM			

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